

HALOGEN

FREE

Hyperfast Rectifier, 30 A FRED Pt®



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)} 30 A					
V_R	600 V				
V _F at I _F	1.40 V				
t _{rr} (typ.)	22 ns				
T _J max.	175 °C				
Package	TO-3PF				
Circuit configuration	Common anode				

FEATURES

- · Hyperfast soft recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of switch mode power supplies and inverters (air conditioning, high-frequency welding, UPS, and motor drives)

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: TO-3PF

Molding compound meets UL 94 V-0 flammability rating **Terminals:** matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	V _{RRM}		600	V		
Average rectified forward current in DC	I _{F(AV)}		30	^		
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C, both anodes connection	280	A		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-	.,
Forward voltage	M	I _F = 30 A	-	1.70	2.15	- V
	V_{F}	I _F = 30 A, T _J = 150 °C	-	1.40	1.65	
Reverse leakage current	I _R	$V_R = V_R$ rated	-	0.02	10	μА
		T _J = 150 °C, V _R = V _R rated	-	36	300	
Junction capacitance	C _T	V _R = 600 V	-	19	-	pF





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A}$		A/μs, V _R = 30 V	-	22	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	90	-	ns
		T _J = 125 °C	$I_F = 30 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_B = 400 \text{ V}$	-	110	-	
Dook recovery ourrent	urrent I _{RRM}	T _J = 25 °C		-	4.1	-	Α
Peak recovery current		T _J = 125 °C		-	9.4	-	_ A
Reverse recovery charge Q _{rr}	T _J = 25 °C		-	230	-	nC	
	Qrr	T _J = 125 °C		-	730	-	I IIC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction-to-case	R _{thJC}	R _{thJC}		2.30	2.90	
Thermal resistance, junction-to-ambient	R _{thJA}	Typical socket mount		30	-	°C/W
Typical thermal resistance, case-to-heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-	
Maight			-	6.2	-	g
Weight			-	0.21	-	oz.
Mounting torque			4 (3.5)	-	6 (5.3)	kgf · cm (lbf · in)
Marking device		Case style TO-3PF	AZH3106FP			



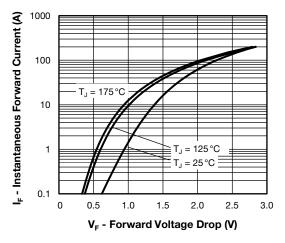


Fig. 1 - Forward Voltage Drop Characteristics

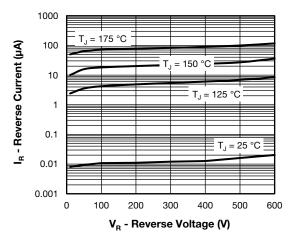


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

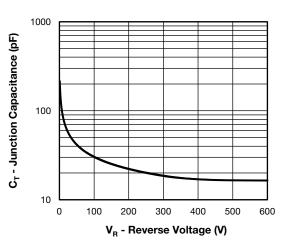


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

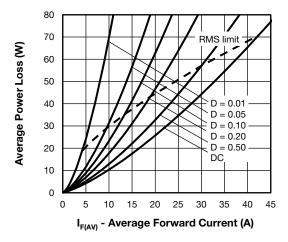


Fig. 4 - Forward Power Loss Characteristics

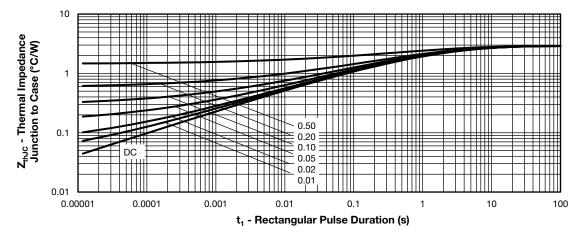


Fig. 5 - Transient Thermal Impedance, Junction to Case



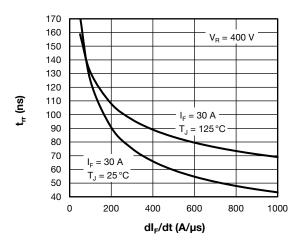


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

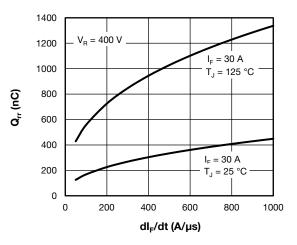


Fig. 7 - Typical Reverse Recovery Charge vs. dl_F/dt

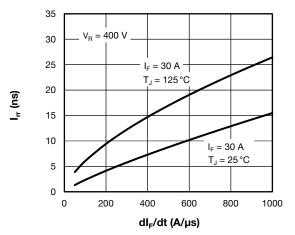


Fig. 8 - Typical Reverse Recovery Current vs. dl_F/dt

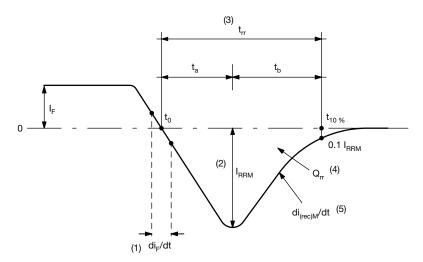


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

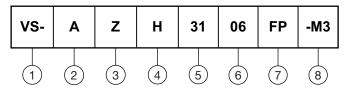
- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ Q_{rr} area under curve defined by t_0 and t_{10} %

$$Q_{rr} = \int_{t_0}^{t_{10} \%} I(t) dt$$

(5) di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Circuit configuration:

A = single diode, double anode

Z = TO-3FP package

4 - H = hyperfast recovery time

5 - Current code: 31 = 30 A

Voltage code: 06 = 600 V

7 - FP = FullPAK

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96691</u>					
Part marking information	www.vishay.com/doc?96690				



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